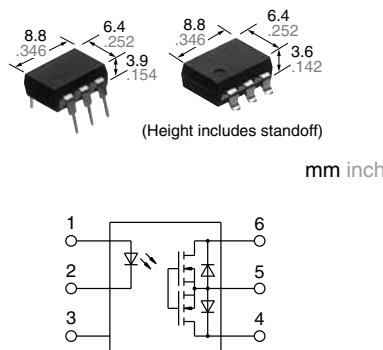




**Capable of 2A to 3A
high-frequency load
switching**

**PhotoMOS®
HE 1 Form A
High Capacity (AQV251G, AQV252G)**



FEATURES

1. Greatly increased load current in a compact DIP package
Continuous load current: 3.5A (AQV251G)
2. Greatly improved specifications allow you to use this in place of mercury and mechanical relays.
3. Low on-resistance (Typ. 35mΩ, AQV251G)

TYPICAL APPLICATIONS

- Measuring instrument market (Testers etc.)
- Industrial machinery and equipment
- Power supply controls
- Security/Disaster prevention market I/O sections of warning devices, security systems, etc.

RoHS compliant

TYPES

	Output rating*		Package	Part No.				Packing quantity
				Through hole terminal		Surface-mount terminal		
	Load voltage	Load current		Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	
AC/DC dual use	30 V	3.5 A	DIP6-pin	AQV251G	AQV251GA	AQV251GAX	AQV251GAZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.
	60 V	2.5 A	DIP6-pin	AQV252G	AQV252GA	AQV252GAX	AQV252GAZ	1,000 pcs.

*Indicate the peak AC and DC values.

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

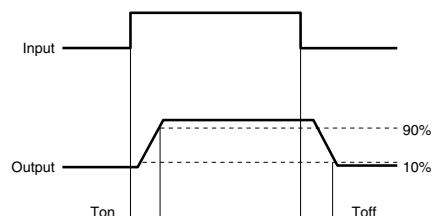
Item		Symbol	Type of connection	AQV251G(A)	AQV252G(A)	Remarks
Input	LED forward current	I _F	A	50 mA		
	LED reverse voltage	V _R		5 V		
	Peak forward current	I _{FP}		1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}		75 mW		
Output	Load voltage (peak AC)	V _L	A	30 V	60 V	
	Continuous load current	I _L		3.5 A	2.5 A	A connection: Peak AC, DC B, C connection: DC
	Peak load current	I _{peak}		4.0 A	3.5 A	
	Power dissipation	P _{out}	C	6.0 A	5.0 A	
Total power dissipation		P _T		6.0 A		100ms (1 shot), V _L = DC
I/O isolation voltage		V _{iso}		600 mW		
Ambient temperature		T _{opr}		650 mW		
Operating		T _{stg}		1,500 Vrms		
Storage				-40 to +85°C -40 to +185°F		(Non-icing at low temperatures)
				-40 to +100°C -40 to +212°F		

HE 1 Form A High Capacity (AQV251G, AQV252G)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV251G(A)	AQV252G(A)	Condition
Input	LED operate current	Typical Maximum	I_{Fon}	—	0.55 mA 3 mA	0.5 mA
	LED turn off current				0.2 mA 0.45 mA	$I_L = 100\text{mA}$
	LED dropout voltage	Typical	V_F	—	1.14 V (1.32 V at $I_F = 50\text{ mA}$)	
		Maximum			1.5 V	$I_F = 5\text{ mA}$
Output	On resistance	Typical	R_{on}	A	0.035 Ω 0.08 Ω	0.08 Ω
		Maximum			0.018 Ω 0.04 Ω	0.12 Ω 0.06 Ω
		Typical	R_{on}	B	0.01 Ω	0.04 Ω
		Maximum			0.02 Ω	0.06 Ω
		Typical	R_{on}	C	0.01 Ω	0.02 Ω
	Off state leakage current	Maximum	I_{Leak}	—	0.03 Ω	$I_F = 0\text{ mA}, V_L = \text{Max.}$
Transfer characteristics	Turn on time*	Typical	T_{on}	—	1.1 ms 5.0 ms	$I_F = 5\text{ mA}, I_L = 100\text{ mA}$ $V_L = 10\text{ V}$
	Turn off time*	Typical			0.1 ms 0.5 ms	$I_F = 5\text{ mA}, I_L = 100\text{ mA}$ $V_L = 10\text{ V}$
	I/O capacitance	Typical	C_{iso}	—	0.8 pF	$f = 1\text{ MHz}$ $V_B = 0\text{ V}$
		Maximum			1.5 pF	
	Initial I/O isolation resistance	Minimum	R_{iso}	—	1,000 MΩ	500 V DC
	Max. operating frequency	Maximum	—	—	10 cps	$I_F = 5\text{ mA}, \text{duty} = 50\%$ $V_L \times I_L = 100\text{ V}\cdot\text{A}$

*Turn on/Turn off time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

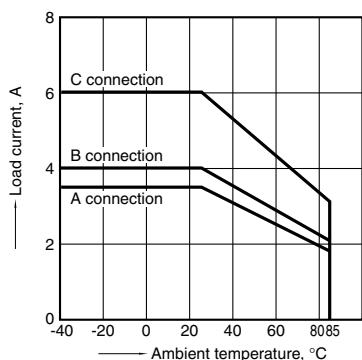
Item	Symbol	Min.	Max.	Unit
AQV251G(A)	LED current	I_F	5	30
	Load voltage (Peak AC)	V_L	—	24
AQV252G(A)	Continuous load current (A connection)	I_L	—	3.5
	Load voltage (Peak AC)	V_L	—	48
		I_L	—	2.5

■ These products are not designed for automotive use.

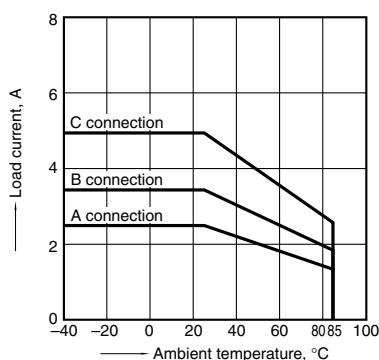
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

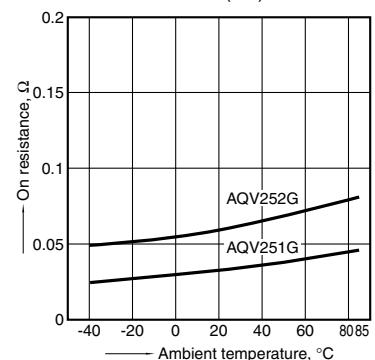
1.-(1) Load current vs. ambient temperature characteristics
 Tested sample: AQV251G;
 Allowable ambient temperature: -40 to +85°C
 -40 to +185°F



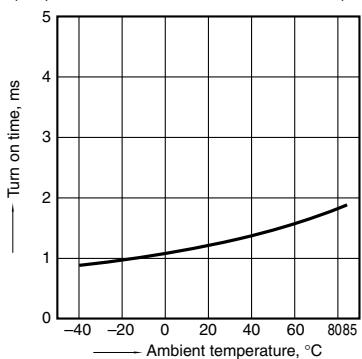
1.-(2) Load current vs. ambient temperature characteristics
 Tested sample: AQV252G;
 Allowable ambient temperature: -40 to +85°C
 -40 to +185°F



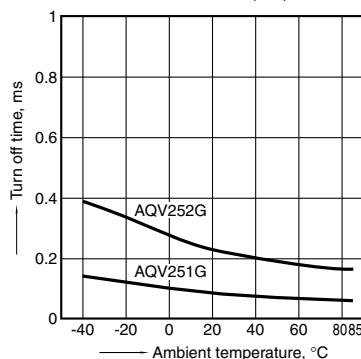
2. On resistance vs. ambient temperature characteristics
 Measured portion: between terminals 4 and 6;
 LED current: 5 mA; Load voltage: Max. (DC)
 Continuous load current: Max.(DC)



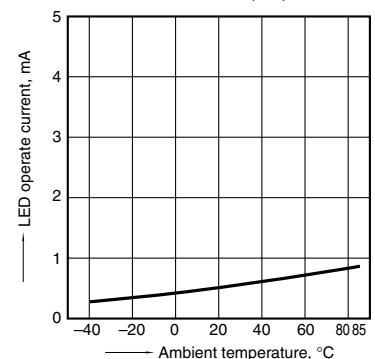
3. Turn on time vs. ambient temperature characteristics
 Tested sample: All; LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



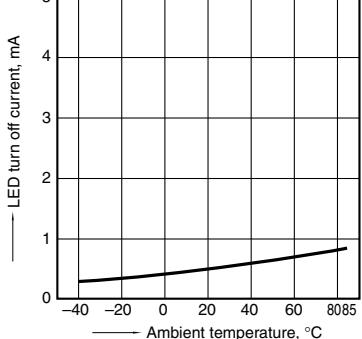
4. Turn off time vs. ambient temperature characteristics
 LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



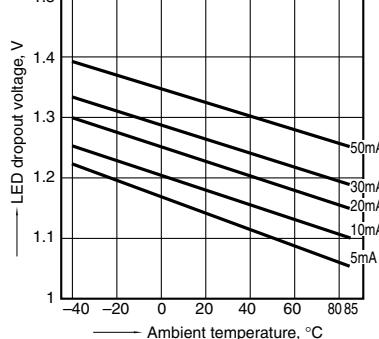
5. LED operate current vs. ambient temperature characteristics
 Tested sample: All; Load voltage: 10 V (DC); Continuous load current: 100mA (DC)



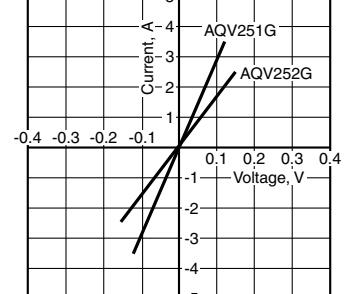
6. LED turn off current vs. ambient temperature characteristics
 Tested sample: All; Load voltage: 10 V (DC); Continuous load current: 100mA (DC)



7. LED dropout voltage vs. ambient temperature characteristics
 Tested sample: All;
 LED current: 5 to 50 mA



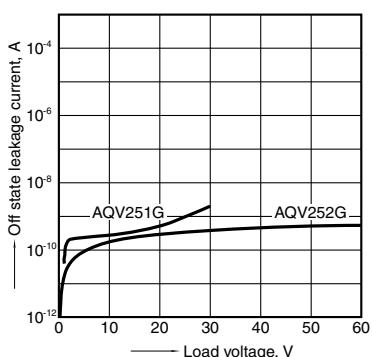
8. Current vs. voltage characteristics of output at MOS portion
 Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



HE 1 Form A High Capacity (AQV251G, AQV252G)

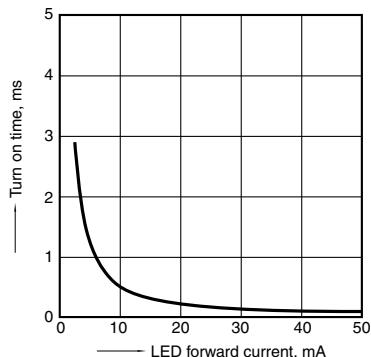
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



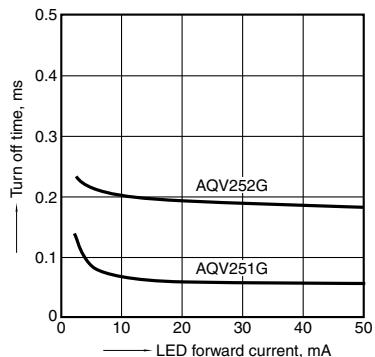
10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Tested sample: All; Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



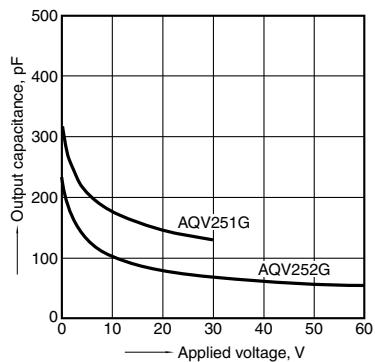
11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



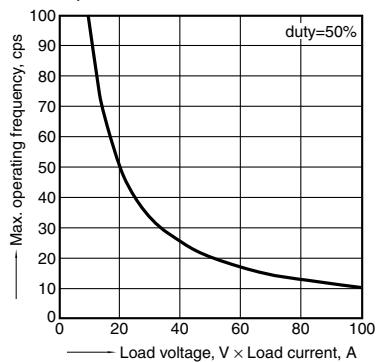
12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F



13. Max. operating frequency vs. load voltage and current characteristics

Tested sample: AQV251G;
LED current: 5 mA;
Ambient temperature: 25°C 77°F



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